**Research Article**

**Gold-Catalyzed Growth of Aluminium-Doped Zinc Oxide Nanorods by Sputtering Method**

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Aluminium-doped zinc oxide (AZO) nanorods thin films were grown by RF magnetron sputtering on gold (Au) metal catalyst. The Au catalyst layers with 5, 10, and 15 nm thickness were deposited on glass substrates by sputtering method followed by annealing for 15 min at 500°C to form Au nanostructures on the glass substrate. The AZO thin films were then deposited on the Au catalyst at different deposition temperature varying from 200 to 500°C. Postdeposition annealing processes of the Au catalyst resulted in different morphologies of the Au catalyst layers depending on their thicknesses. This in turn gave different AZO morphologies which suggest that the Au catalyst layer thickness and the deposition temperature contribute to the growth mechanism of the AZO nanostructures. AZO nanorods thin films having hexagonal wurtzite structure with individual nanorods on the film surface were obtained from the samples deposited on 5 and 10 nm thick Au catalyst with the deposition temperature of 300°C.

1. **Introduction**

Transparent conductive oxide (TCO) films have been extensively studied on a broad range of applications due to their low resistivity and high transmittance of visible light [1]. Among the various TCO films, aluminium-doped zinc oxide (AZO) is one of the promising materials for industrial use due to its advantages such as low cost and nontoxicity as well as exhibiting good stability in hydrogen plasma [1–4]. There are various techniques to deposit AZO nanorod thin films such as sol-gel [5], plasma enhanced chemical vapour deposition (CVD) [6], and RF-sputtering [7]. Of all mentioned deposition techniques, the RF magnetron sputtering is the least investigated for the fabrication of 1D nanostructures whereas it is most widely used to deposit uniform thin film [8]. To allow compatibility of nanorods growth with the matured CMOS manufacturing technology, we therefore explored the growth of nanorods by sputtering method. In this work, the AZO nanostructures were deposited using RF-sputtering method assisted by gold (Au) catalyst due to a large number of reports of Au-catalyst assisted growth of nanorods by CVD methods [9–11] although the reports on sputtering are limited. The thickness of the Au catalyst layer was varied from 5 to 15 nm, and, for comparison, deposition on bare glass was also carried out. The deposition temperatures were varied from 200 to 500°C, which are relatively lower compared to other reported growth temperatures [12].

2. **Experimental**

In this research, Au catalyst was used to initiate and enhance the nanorods growth. Au catalyst layers with 5, 10, and 15 nm thickness were deposited on glass substrates by a sputter coater. Prior to Au catalyst deposition process, the substrates were subjected to cleaning process in ultrasonic bath for 10 min at 50°C using acetone, methanol, and deionized water (DIW) in sequence to ensure that the substrates are free from dirt and contamination. Then the deposited Au layers were annealed at 500°C in a furnace for 15 min in ambient air. The AZO thin films were then deposited on the Au catalyst layer by radio frequency (RF) magnetron sputtering which used high purity ceramic target with 98% of ZnO doped with 2% of Al₂O₃. RF power of 200 W was used throughout.
the process and pressure inside the chamber was 0.5 Pa. The deposition temperatures during sputter were varied from 200 to 500°C. The argon (Ar) gas was used as the sputtering gas with the flow rate set to 20 sccm. A presputtering time of 10 min was used in order to ensure the stabilization of sputtering conditions.

Field effect scanning electron microscope (FESEM, JEOL JSM 7600F) was used to observe the surface morphology and cross-section of the AZO nanostructures while energy dispersive X-ray spectroscopy (EDX) is used to determine the elemental compositions of AZO thin films. The crystal structure of the films was analyzed by using X-ray diffractometer (XRD, Rigaku Ultima IV with a Cu Kα), in which \( \lambda = 0.15406 \) nm, and also Raman spectroscopy.

3. Results and Discussion

3.1. Effect of Au Catalyst Thickness. Figure 1(a) shows the Au catalyst layer morphology before annealing and Figures 1(b)–1(d) show those after annealing for 15 min in ambient air for the thickness of 5, 10, and 15 nm, respectively. The Au layer for nonannealed sample was dense and continuous. We can see that the annealing process restructured the Au layer and formed island morphologies with different sizes. From the inset, it can be seen that the Au particles sizes were increased from 63.8 nm to 115 nm when the thickness of Au layer was increased from 5 nm to 15 nm, respectively, suggesting that the layer thickness influenced the size of the particle.

Figures 2(a), 2(b), 2(c), and 2(d) show the AZO nanostructures grown on bare glass and also on 5, 10, and 15 nm thick Au catalysts deposited at 300°C, respectively. From Figure 2(a), it can be seen that a dense and continuous AZO thin film is grown on the bare glass without any formation of nanostructures. On the other hand, unoriented individual AZO nanorods can be seen on the sample surface which was deposited on the 5 nm Au catalyst as shown in Figure 2(b). However, the AZO nanorods density decreases when the Au catalyst thickness was increased to 10 and 15 nm, respectively. Comparing the thin films on glass and on 5 nm Au catalyst, it can be said that the Au catalyst facilitates the nucleation sites for the AZO nanorods growth on the 5 nm sample.

The FESEM cross-section images of the samples shown in Figures 3(a), 3(b), 3(c), and 3(d) clearly exhibit the columnar growth of the AZO nanorods thin films, especially for the films grown on the 5 and 10 nm Au catalyst layers. We can see that the film grown on the bare substrate is dense proving the role of the Au catalyst layer on the formation of the nanorods. The thicknesses of the AZO thin films from the cross-section are 602, 578, 641, and 683 nm, respectively. It can be said that increasing the Au catalyst thickness from 5 to 15 nm will cause the AZO thin films to increase. This effect is due to the surface diffusion that caused the deposited particles to stack and rearrange [13]. These columnar structures are also reported...
Figure 2: FESEM surface morphology of AZO nanostructured thin film on (a) bare glass and (b) 5, (c) 10, and (d) 15 nm of Au catalyst layer.

by other researches using sputtering deposition [14, 15] but with different surface morphology.

3.1.1. EDX Spectra. The EDX characterization was done to further study the material components of the AZO samples. Although the weight percentage (wt%) values shown in figures may not be taken as absolute values, relative comparison can be made between the samples. The EDX results for AZO nanorods thin films grown on 5, 10, and 15 nm shown in Figures 4(a), 4(b), and 4(c) confirmed that the films contain aluminium (Al), zinc (Zn), and oxygen (O$_2$) elements. Carbon (C) peak observed from the sample on 5 nm Au may form contamination in the environment. We expected Au peak from the spectra but no Au peak was observed; thus the growth mechanism of the individual nanorods on the surface may be different from the vapour-liquid-solid (VLS) growth [16, 17].

3.1.2. Crystalline Quality. XRD patterns of the AZO nanorods thin films on 5 and 10 nm thicknesses of Au catalyst are shown in Figure 5. From the figure, it can be seen that both samples showed a major peak at 34.4° without any impurity phase found. This peak indicates the ZnO (002) wurtzite hexagonal peak [18, 19]. The XRD patterns do not show significant difference between the two samples.

Figure 6 shows the Raman spectra of AZO nanostructured on 5, 10, and 15 nm Au catalyst at the range of 100–1000 cm$^{-1}$. From the figure, there are 3 similar peaks occurring for all samples at 437.58, 577.35, and 756.49 cm$^{-1}$. The peak at 437.58 cm$^{-1}$ is assigned as optical phonon $E_2$ that corresponds to the wurtzite hexagonal phase of ZnO. This peak supports the XRD result that shows the crystalline quality at (002) which belongs to ZnO wurtzite hexagonal structure. The dominated peak at 577.35 cm$^{-1}$ is attributed as $E_{1L}$ was also observed for all samples. The appearance of $E_{1L}$ mode is supposed to be due to the structural defects. The appearance of another peak at 756.49 cm$^{-1}$ is attributed to local vibration of Al ion in ZnO lattice as a substitution of Al into Zn position.

3.2. Effect of Deposition Temperature. Figures 7(a), 7(b), 7(c), and 7(d) show the AZO thin films deposited at 200, 300, 400, and 500°C, respectively. From Figures 7(a), 7(c), and 7(d), it can be seen that the AZO thin films grown at 200, 400, and 500°C are dense without any growth of nanorods observed, while a random AZO nanorods growth can be observed on AZO thin film deposited at 300°C. Increasing the deposition temperature from 200 to 500 caused the deposition rate of AZO thin films to increase from 16.5 to 22.1 nm/min. This increase of AZO thin films deposition rate is due to the particles gaining the higher energy as the deposition temperature increased. Theoretically, the growth of AZO nanorods is depending on the substrate temperature. Therefore, we hypothesize that, at 200°C, the deposition
Figure 3: FESEM cross-section morphology of AZO nanostructured thin film on (a) bare glass and (b) 5, (c) 10, and (d) 15 nm of Au catalyst layer.

Figure 4: AZO EDX spectra on (a) 5 nm, (b) 10 nm, and (c) 15 nm of Au catalyst.
Figure 5: XRD pattern of AZO thin films prepared at different Au catalyst thickness.

Figure 6: Raman spectra of AZO nanostructured on (a) 5, (b) 10, and (c) 15 nm of Au catalyst.

3.2.1. Crystalline Quality. The XRD patterns of the AZO thin films with regards to temperature changes are shown in Figure 8. All samples showed a major peak at around 34.4–34.5° without any impurity phase found. With increasing temperature from 200 to 500°C, the angle of measured diffraction peaks does not change significantly; however, the intensities of these peaks become more intense and sharper when the substrate temperature is increased from 200 to 400°C. Ma et al. reported that this may happen because the crystallinity of the AZO sample is improved and crystallite sizes become larger when the substrate temperature is increased [20]. The intensity began to decrease as the deposition temperature increased to 500°C. This implies that the crystalline quality increased with the temperature which is acceptable since the higher deposition temperature supplies sufficient energy to the arriving atoms and molecules to arrange themselves to form a uniform crystal orientation. However further increasing the temperature might induce the transition of crystal orientation and thus deteriorate the crystalline quality [21].

Table 1 shows the crystallite size for each sample at different substrate temperature. From Table 1, it can be seen that the crystallite size was increased from 0.50 to 0.57 nm when the substrate temperature was increased from 200 to 500°C. It is in accordance with the fact that the deposited particles get more energy to migrate into the lattice position. This crystallite size was calculated by using Scherrer equation [22]. Consider

$$D = \frac{0.94\lambda}{\beta \cos \theta},$$

where $D$ is the crystallite size, 0.94 is the constant, and $\lambda$ is the wavelength of X-ray which used copper (Cu) source. Then $\beta$ is the FWHM and $\theta$ is the diffraction angle where the peaks are observed from XRD.

4. Conclusion

AZO nanorod thin films were deposited by sputtering method on Au catalyst layers. The effects of the Au catalyst layers thickness and also the deposition temperature on the physical morphologies of the AZO nanorod thin films were studied. AZO thin films having distinct columnar structures were deposited and individual nanorods were observed on the surface of the AZO thin films deposited on the Au catalyst. This phenomenon was not observed for the AZO thin film deposited on bare glass, which confirmed the role of the Au catalyst on the formation of the columnar nanorods. Besides the Au catalyst layer, the AZO deposition temperature also influenced the morphology of the film and also the thin film crystallite size. The AZO nanorods thin films with individual nanorods on the surface were grown on a 5 nm...
The deposited AZO thin films exhibit crystalline structure with wurtzite hexagonal orientation as confirmed from the XRD results.

**Conflict of Interests**

The authors declare that there is no conflict of interests regarding the publication of this paper.

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